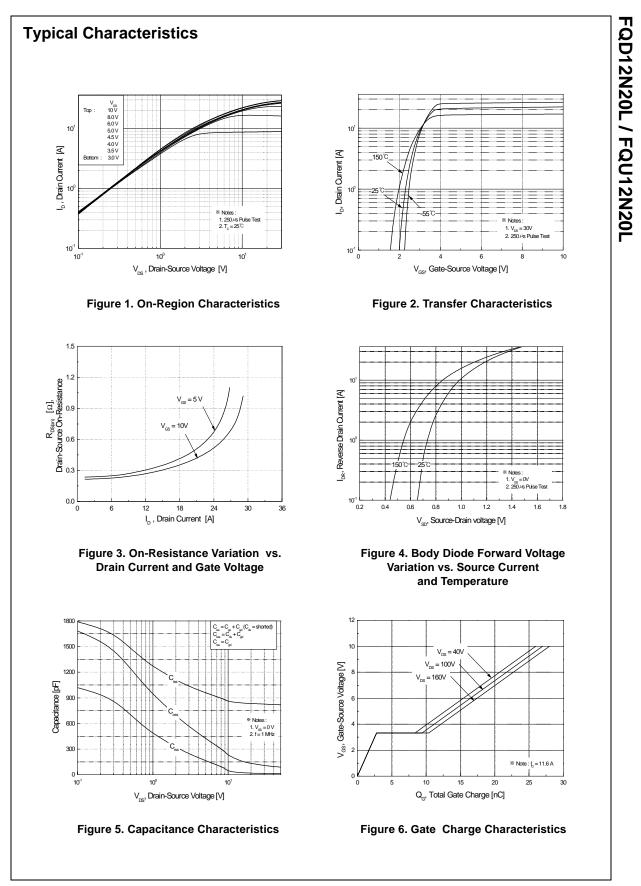
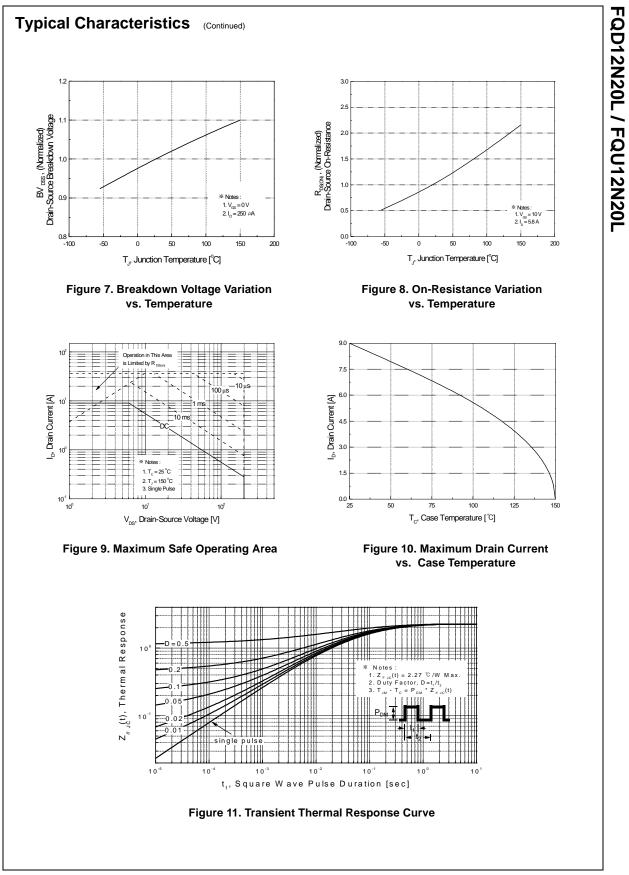
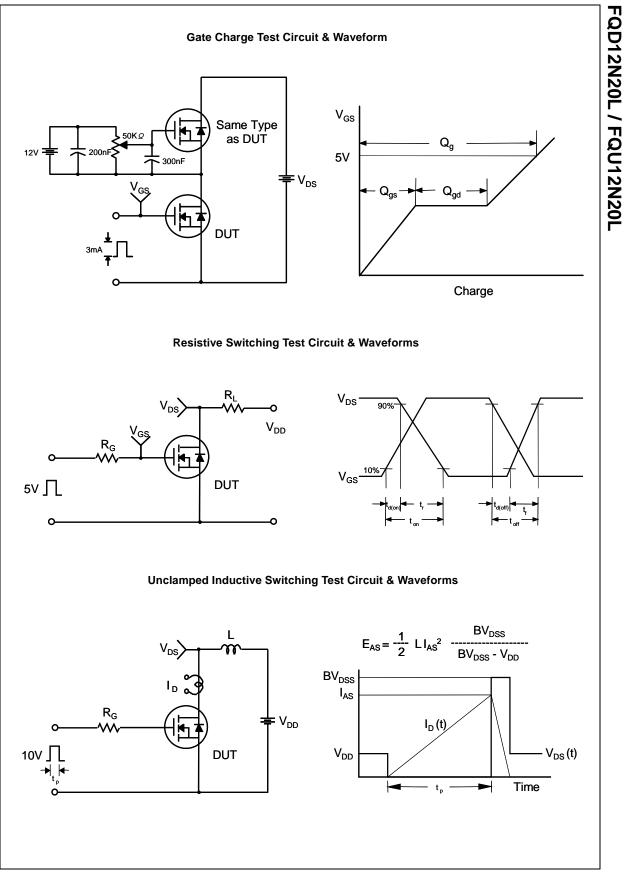


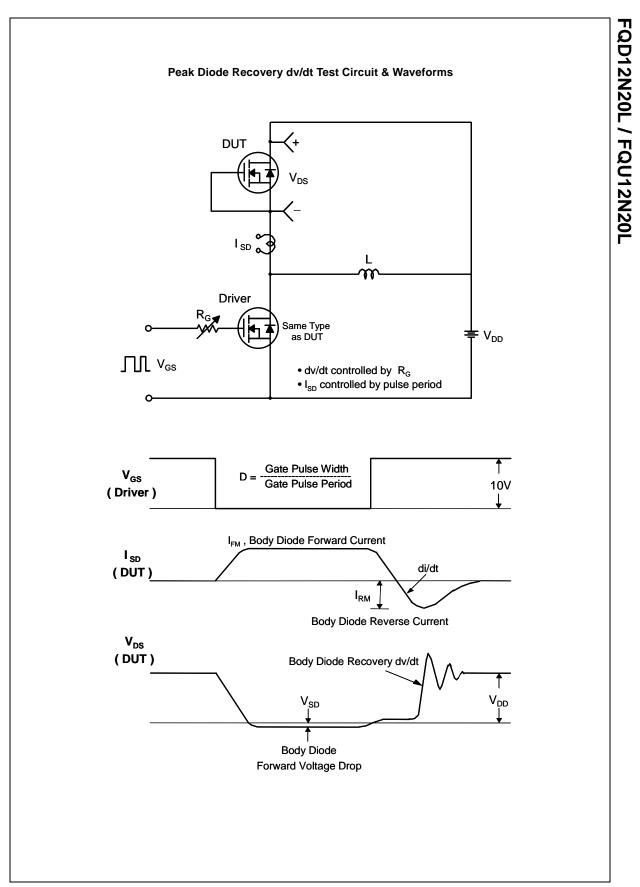
Symbol	Parameter	Test Conditions		Min	Тур	Max	Units
Off Cha	aracteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0 V, I _D = 250 μA		200			V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu$ A, Referenced t	o 25°C		0.14		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 200 V, V _{GS} = 0 V				1	μA
		V _{DS} = 160 V, T _C = 125°C				10	μA
GSSF	Gate-Body Leakage Current, Forward	$V_{GS} = 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$				100	nA
GSSR	Gate-Body Leakage Current, Reverse	$V_{GS} = -20 \text{ V}, V_{DS} = 0 \text{ V}$				-100	nA
On Cha	aracteristics						
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = 250 μA		1.0		2.0	V
R _{DS(on)}	Static Drain-Source	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 4.5 \text{ A}$			0.22	0.28	v
-DS(on)	On-Resistance	$V_{GS} = 5 V, I_D = 4.5 A$			0.22	0.20	Ω
ĴFS	Forward Transconductance	$V_{DS} = 30 \text{ V}, \text{ I}_{D} = 4.5 \text{ A}$	(Note 4)		11.6		S
	ic Characteristics						
C _{iss}	Input Capacitance	$V_{DS} = 25 V, V_{GS} = 0 V,$ f = 1.0 MHz			830	1080	pF
C _{oss}	Output Capacitance				120	155	pF
C _{rss}	Reverse Transfer Capacitance				17	22	pF
Switchi	ing Characteristics						
t _{d(on)}	Turn-On Delay Time	V = 100 V I = 11 6 A			15	40	ns
t _r	Turn-On Rise Time	V_{DD} = 100 V, I _D = 11.6 A, R _G = 25 Ω			190	390	ns
d(off)	Turn-Off Delay Time				60	130	ns
f	Turn-Off Fall Time	(1	Note 4, 5)		120	250	ns
Qg	Total Gate Charge	V _{DS} = 160 V, I _D = 11.6 A,			16	21	nC
Q _{gs}	Gate-Source Charge	V _{GS} = 5 V			2.8		nC
Q _{gd}	Gate-Drain Charge	(1	Note 4, 5)		7.6		nC
		- I Marine Dating					
Drain-S	Source Diode Characteristics an Maximum Continuous Drain-Source Did	•				9.0	A
SM		Maximum Pulsed Drain-Source Diode Forward Current				36	A
V _{SD}		$V_{GS} = 0 \text{ V}, \text{ I}_{S} = 9.0 \text{ A}$				1.5	V
							ns
		$dI_{F}/dt = 100 A/\mu s$	(Note 4)				
t_{rr} Q _{rr} otes: Repetitive R L = 3.9mH, I I _{SD} \leq 11.6A Pulse Test :	$\label{eq:response} \begin{array}{ c c c } \hline Reverse Recovery Time \\ \hline Reverse Recovery Charge \\ \hline Reverse Recovery Reverse \\ \hline Reverse Recovery Reverse \\ \hline Reverse Recovery Reverse \\ \hline Reverse Reverse \\ \hline Reverse Recovery Reverse \\ \hline Reverse Reverse \\ \hline R$		(Note 4)		128 0.56		ns μC

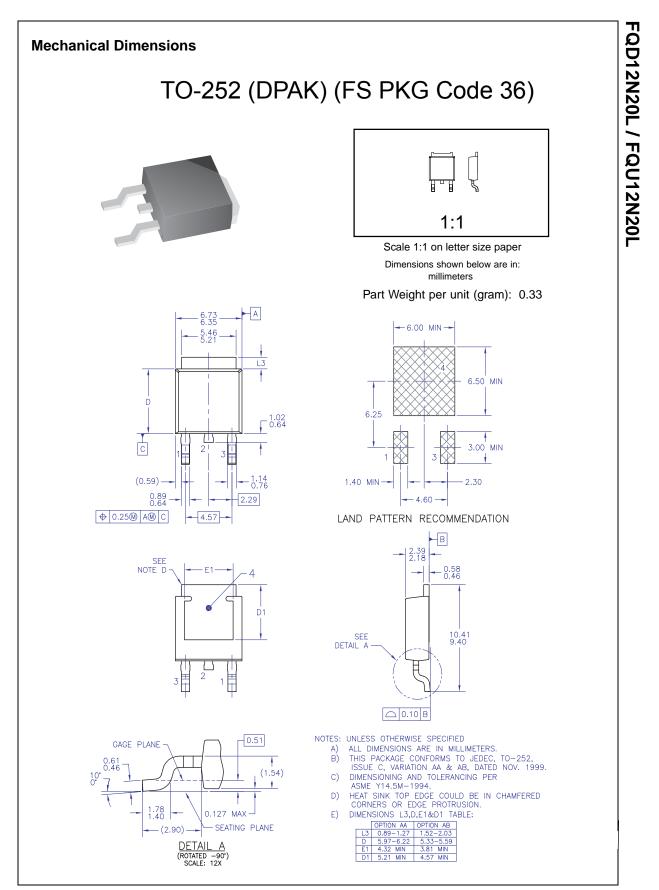
FQD12N20L / FQU12N20L



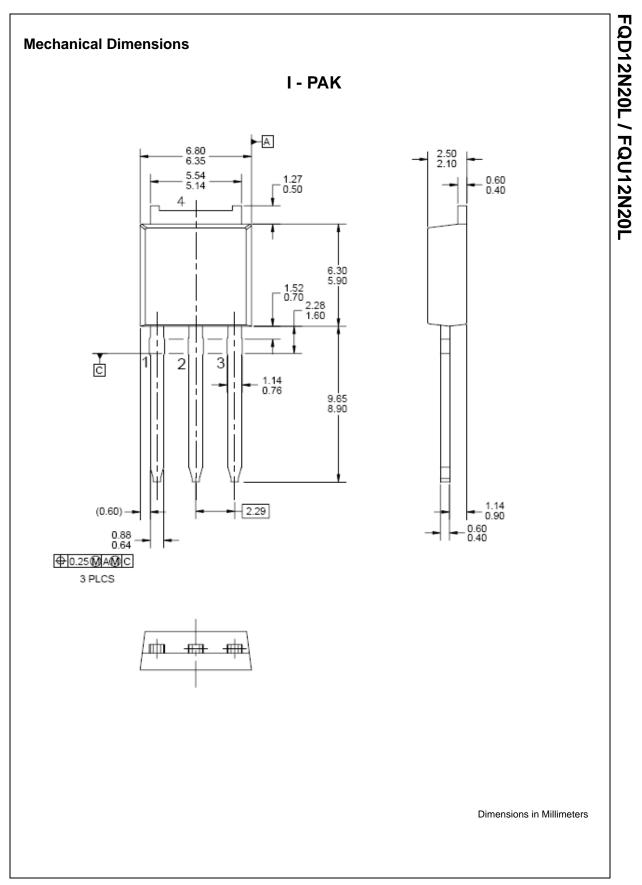








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